



BSS84DW

### **DUAL P-CHANNEL ENHANCEMENT MODE MOSFET**

### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(on) max</sub>	Ι <sub>D</sub> Τ <sub>A</sub> = +25°C
-50V	10Ω @ V <sub>GS</sub> = -5V	-130mA

### **Description**

This MOSFET has been designed to minimize the on-state resistance  $(R_{DS(on)})$  and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

### **Applications**

- General Purpose Interfacing Switch
- · Power Management Functions
- Analog Switch

SOT363



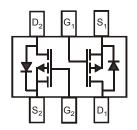
Top View

### **Features and Benefits**

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT363
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Alloy 42 leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.006 grams (approximate)



Top View Internal Schematic

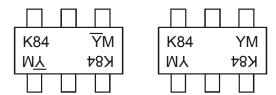
### Ordering Information (Note 4)

Part Number	Compliance	Case	Packaging
BSS84DW-7-F	Standard	SOT363	3,000/Tape & Reel
BSS84DWQ-13	Automotive	SOT363	10,000/Tape & Reel
BSS84DWQ-7	Automotive	SOT363	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

### **Marking Information**



K84 = Product Type Marking Code

YM = Date Code Marking for SAT (Shanghai Assembly/ Test site)
YM = Date Code Marking for CAT (Chengdu Assembly/ Test site)

Y or  $\overline{Y}$  = Year (ex: A = 2013)

M = Month (ex: 9 = September)

Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	K	L	M	N	Р	R	S	Т	U	V	W	Х	Υ	Z
Month	Jan	Fe	b	Mar	Apr	May	Ju	n	Jul	Aug	Sep	Oc	t I	Nov	Dec
Code	1	2		3	4	5	6		7	8	9	0		N	D



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Drain-Source Voltage		$V_{DSS}$	-50	V
Drain-Gate Voltage (Note 5)		$V_{DGR}$	-50	V
Gate-Source Voltage	Continuous	$V_{GSS}$	±20	V
Drain Current (Note 6)	Continuous	$I_{D}$	-130	mA

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 6)	$P_{D}$	300	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

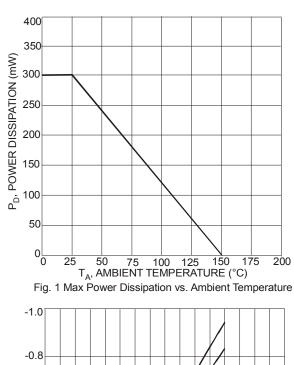
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-50	-75	_	V	$V_{GS} = 0V, I_D = -250\mu A$
		_	_	-1	μA	$V_{DS} = -50V$ , $V_{GS} = 0V$ , $T_{J} = +25$ °C
Zero Gate Voltage Drain Current	Inno	_	_	-2	μA	$V_{DS} = -50V$ , $V_{GS} = 0V$ , $T_{J} = +125$ °C
Zero Gate Voltage Brain Guirent	IDSS	_		-100	nA	$V_{DS} = -25V$ , $V_{GS} = 0V$ , $T_{J} = +25$ °C
Gate-Body Leakage	I <sub>GSS</sub>	_		±10	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)	ē.					
Gate Threshold Voltage	V <sub>GS(th)</sub>	-0.8	-1.6	-2.0	V	$V_{DS} = V_{GS}$ , $I_D = -1mA$
Static Drain-Source On-Resistance	R <sub>DS (ON)</sub>	_	6	10	Ω	$V_{GS} = -5V, I_D = -0.100A$
Forward Transconductance	g <sub>FS</sub>	0.05	_	_	S	$V_{DS} = -25V, I_{D} = -0.1A$
DYNAMIC CHARACTERISTICS	ē.					
Input Capacitance	C <sub>iss</sub>	_		45	рF	
Output Capacitance	Coss	_		25	pF	$V_{DS} = -25V$ , $V_{GS} = 0V$ , $f = 1.0MHz$
Reverse Transfer Capacitance	C <sub>rss</sub>	_	_	12	pF	
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	t <sub>D(ON)</sub>		10		ns	$V_{DD} = -30V$ , $I_D = -0.27A$ ,
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	18	_	ns	$R_{GEN} = 50\Omega$ , $V_{GS} = -10V$

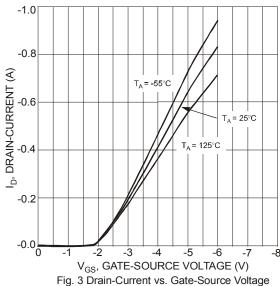
Notes: 5.  $R_{GS} \le 20K\Omega$ .

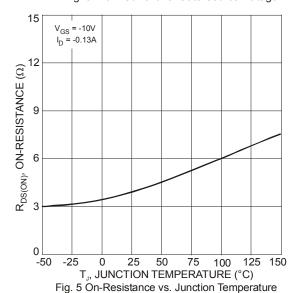
<sup>6.</sup> Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com.

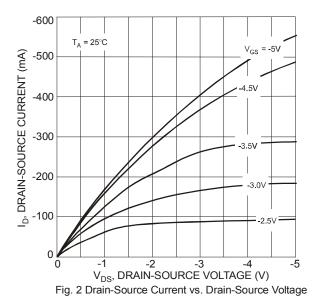
<sup>7.</sup> Short duration pulse test used to minimize self-heating effect.

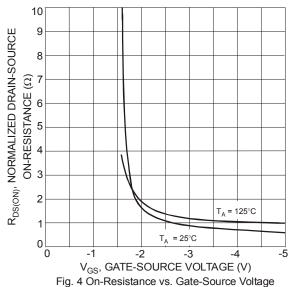


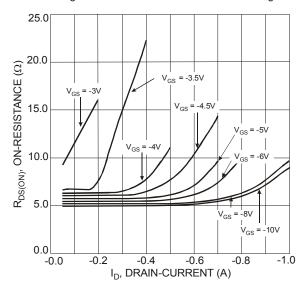








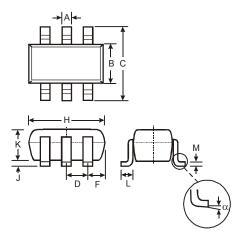






## **Package Outline Dimensions**

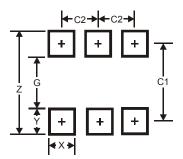
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT363						
Dim	Min	Тур					
Α	0.10	0.30	0.25				
В	1.15	1.35	1.30				
С	2.00	2.20	2.10				
D		0.65 Ty	p				
F	0.40	0.45	0.425				
Н	1.80	2.20	2.15				
J	0	0.10	0.05				
K	0.90	1.00	1.00				
L	0.25	0.40	0.30				
М	0.10	0.22	0.11				
α	0°	8°	-				
All	All Dimensions in mm						

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.5
G	1.3
X	0.42
Y	0.6
C1	1.9
C2	0.65



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